2017 Fall

"Phase Transformation in Materials"

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- **Binary System** mixture/ solution / compound
- Gibbs Free Energy in Binary System

$$G_1 = X_A G_A + X_B G_B \quad J/mol$$
 $G_2 = G_1 + \Delta G_{mix} \quad J/mol$

Ideal solution (\Delta H_{mix} = 0) $\Delta G^{mix} = RT(X_A \ln X_A + X_B \ln X_B)$

$$G = X_A G_A + X_B G_B + RT(X_A \ln X_A + X_B \ln X_B)$$

Regular solution $\Delta H_{mix} = P_{AB} \varepsilon$ where $\varepsilon = \varepsilon_{AB} - \frac{1}{2} (\varepsilon_{AA} + \varepsilon_{BB})$ $G = X_A G_A + X_B G_B + \Omega X_A X_B + RT(X_A \ln X_A + X_B \ln X_B)$

- Chemical potential and Activity

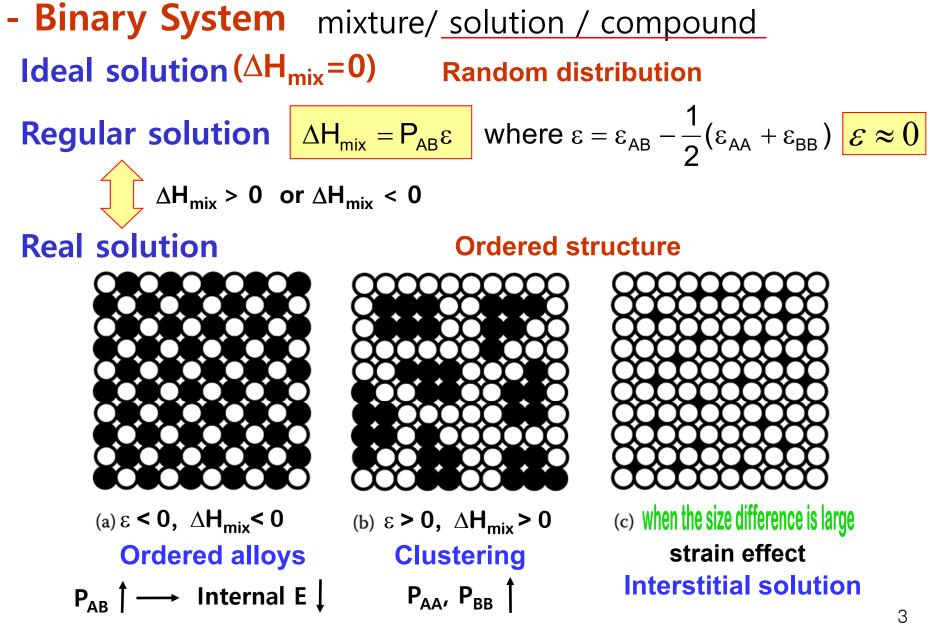
$$\mu_{A} = \left(\frac{\partial G'}{\partial n_{A}}\right)_{T, P, n_{B}}$$

$$\mu_{A} = G_{A} + RT \ln a_{A} \quad \ln \left(\frac{a_{A}}{X_{A}}\right) = \frac{\Omega}{RT} (1 - X_{A})^{2}$$

 $\frac{a_A}{X_A} = \gamma_A = \text{activity coefficient}$

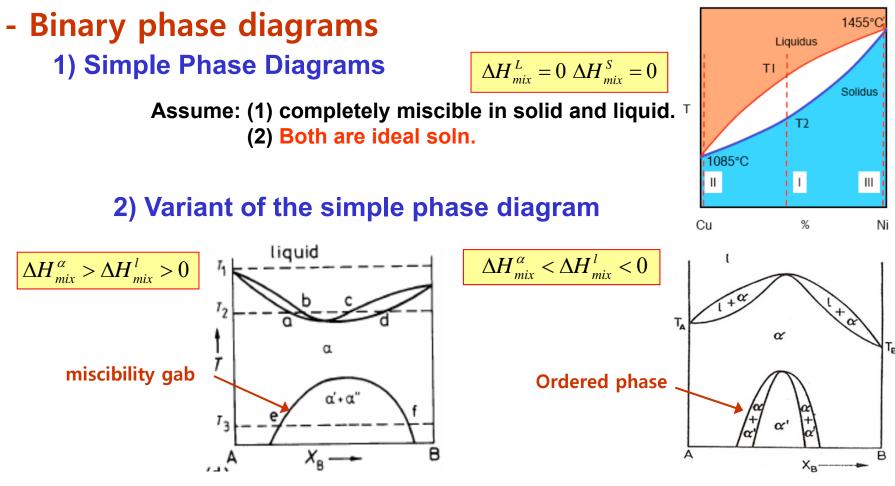
 μ 는 조성에 의해 결정되기 때문에 dn_A 가 매우 작아서 조성변화 없어야

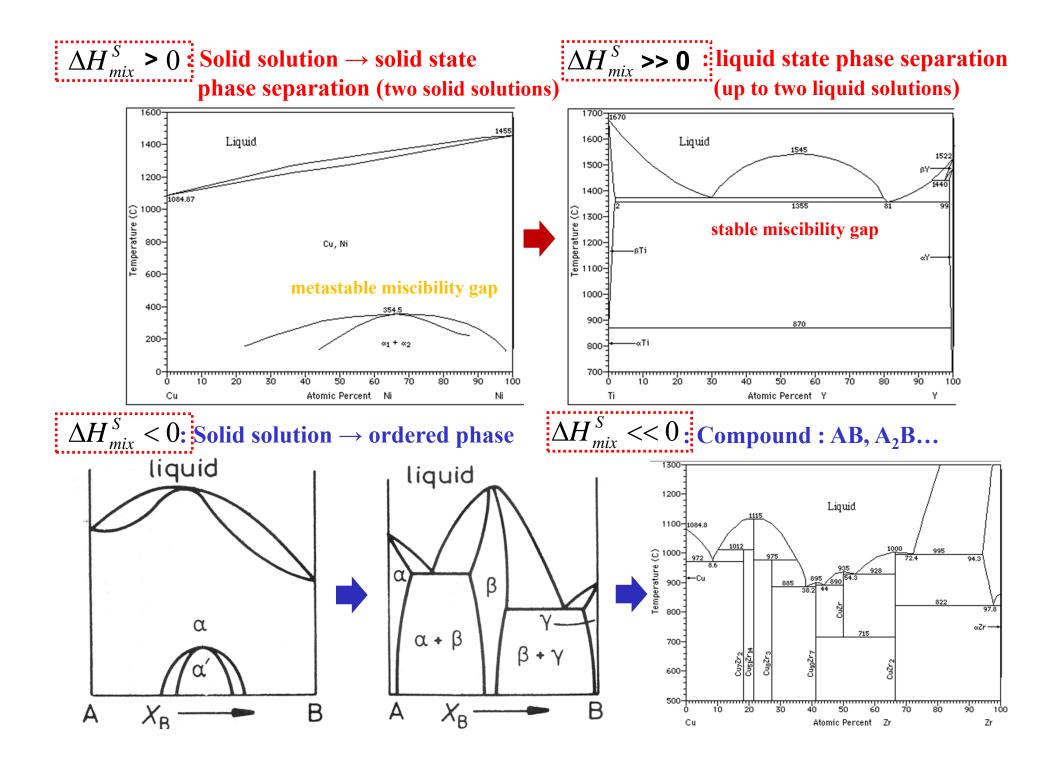
Contents for previous class



- Equilibrium in Heterogeneous Systems

 $G_0^{\beta} > G_0^{\alpha} > G_0^{\alpha+\beta} \implies \alpha + \beta$ separation \implies unified chemical potential





Q5: How can we define equilibrium in heterogeneous systems?

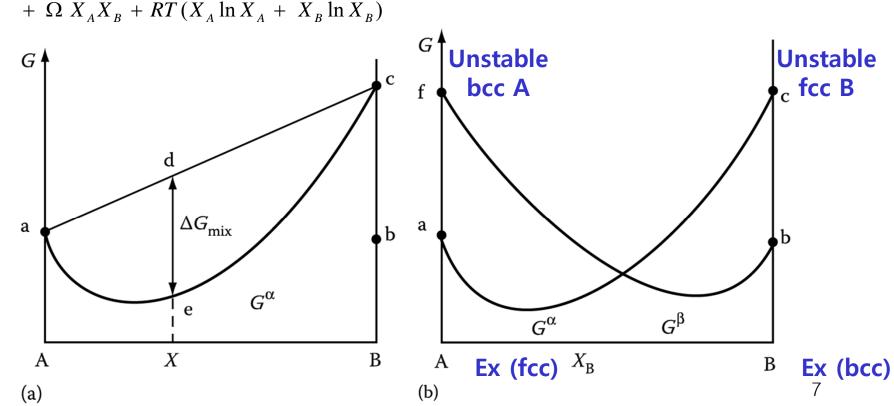
1.4

 $G = X_A G_A + X_B G_B$

Equilibrium in Heterogeneous Systems

A, B different crystal structure \rightarrow two free energy curves must be drawn, one for each structure.

We have dealt with the case where the components A and B have the same crystal structure. What would happen when the components A and B have a different crystal structure? → heterogeneous system





1.4

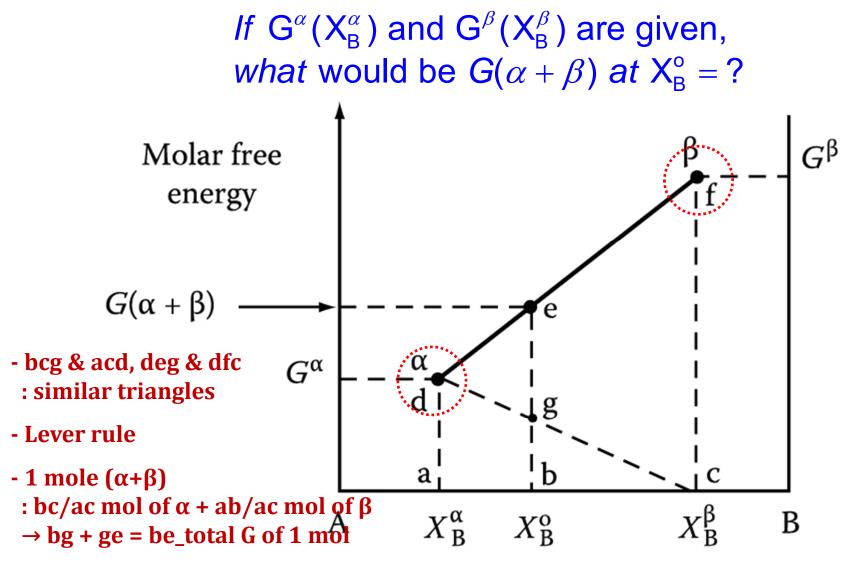
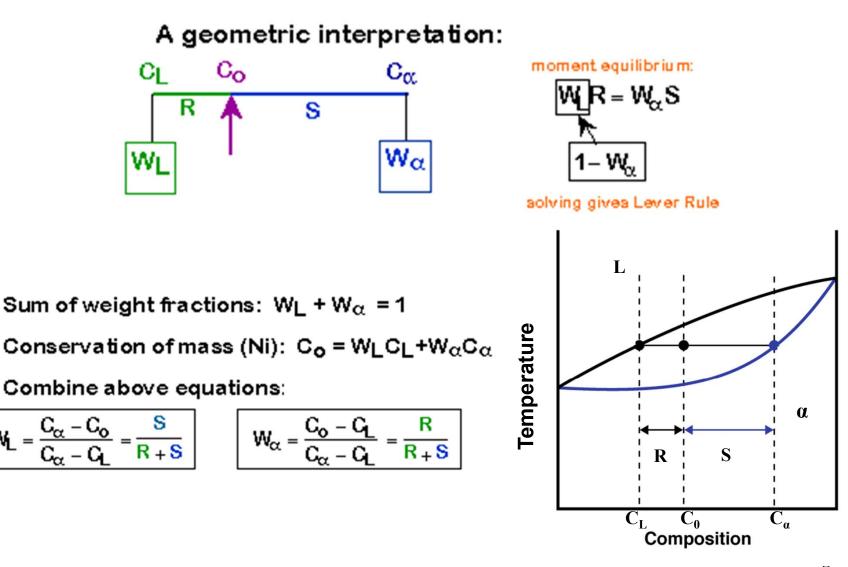


Fig. 1.26 The molar free energy of a two-phase mixture (α + β)

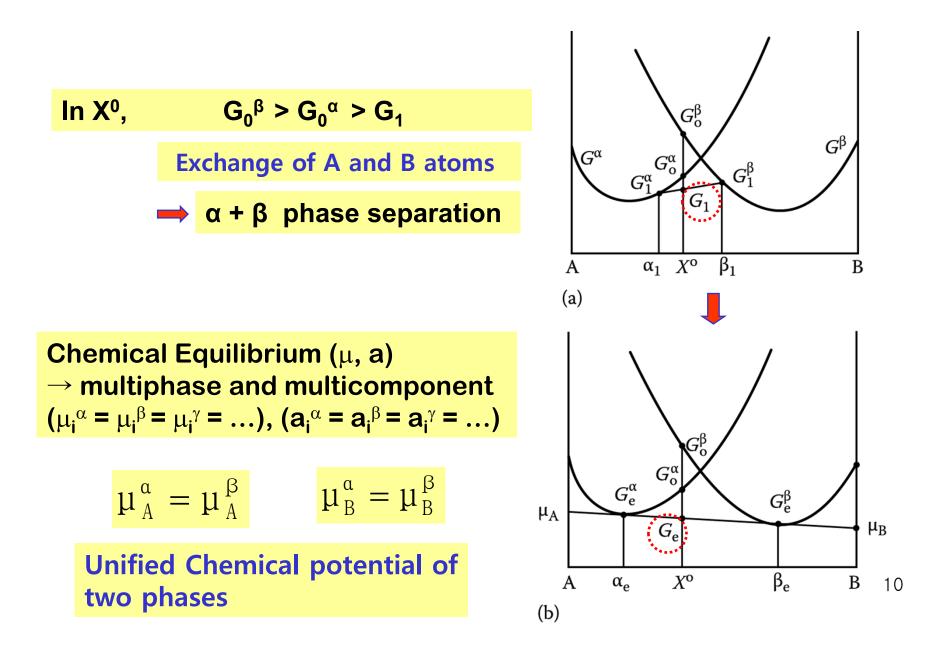
Lever rule



Wi =

1.4

Equilibrium in Heterogeneous Systems



Variation of activity with composition

The most stable state, with the lowest free energy, is usually defined as the state in which the pure component has unit activity of A in pure α .

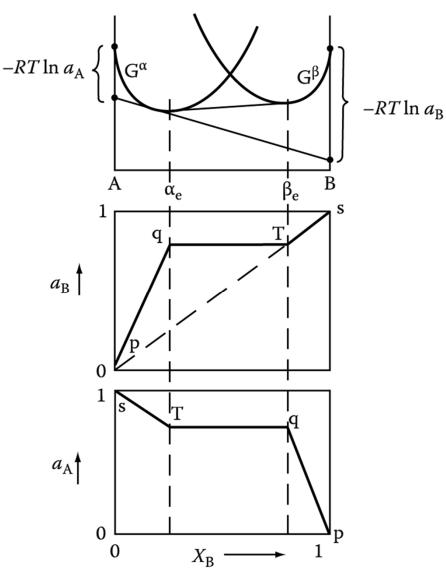
when
$$X_A = 1 \rightarrow a_A^{\alpha} = 1$$

when
$$X_B = 1 \rightarrow a_B^\beta = 1$$

when α and β in equil.

$$\mathbf{a}_{\mathsf{A}}^{\alpha} = \mathbf{a}_{\mathsf{A}}^{\beta}$$

 $\mathbf{a}_{\mathsf{B}}^{\alpha} = \mathbf{a}_{\mathsf{B}}^{\beta}$

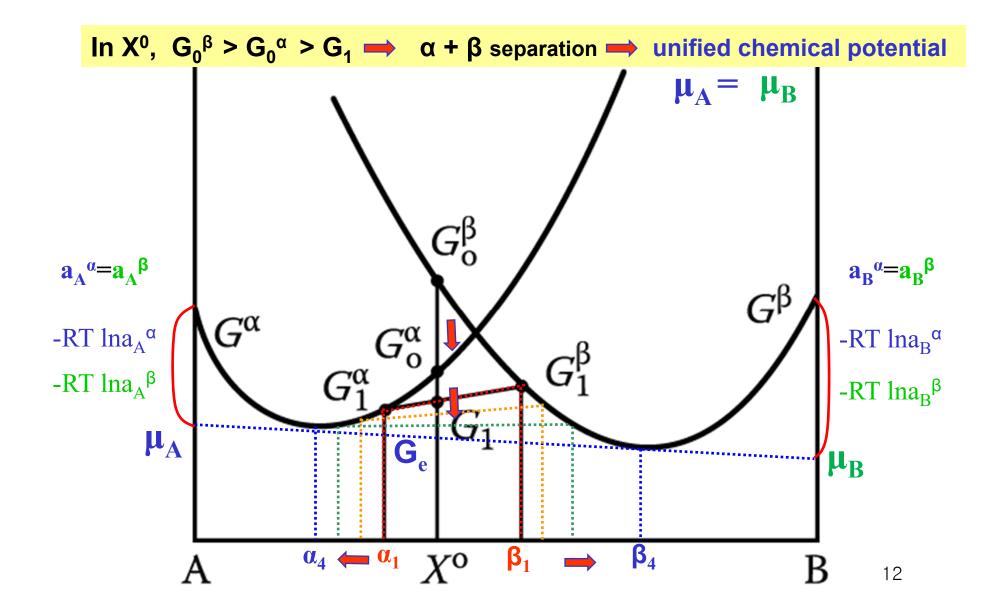


Unified activity of two phase

Fig. 1.28 The variation of a_A and a_B with composition for a binary system containing two ideal solutions, α and β 11

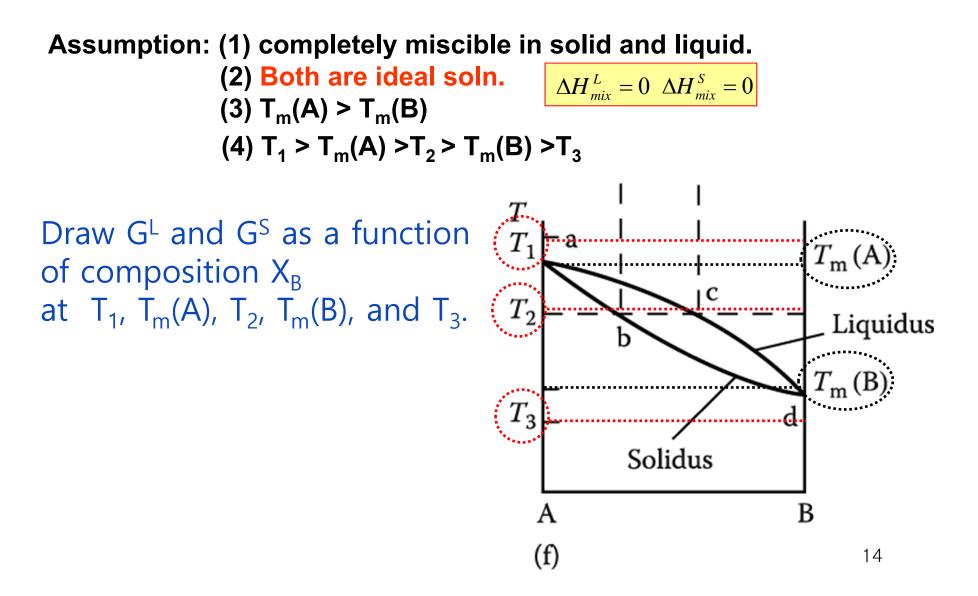
Activity, a : effective concentration for mass action

Equilibrium in Heterogeneous Systems



Q6: How equilibrium is affected by temperature in complete solid solution?

1) Simple Phase Diagrams



1) Simple Phase Diagrams

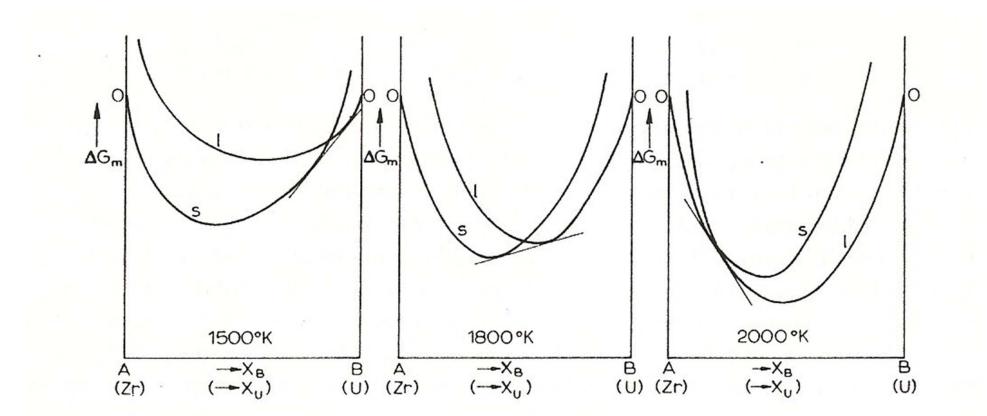


Fig. 26. Free energy curves for liquid and solid phases in the U-Zr system at 1500°, 1800° and 2000 °K.

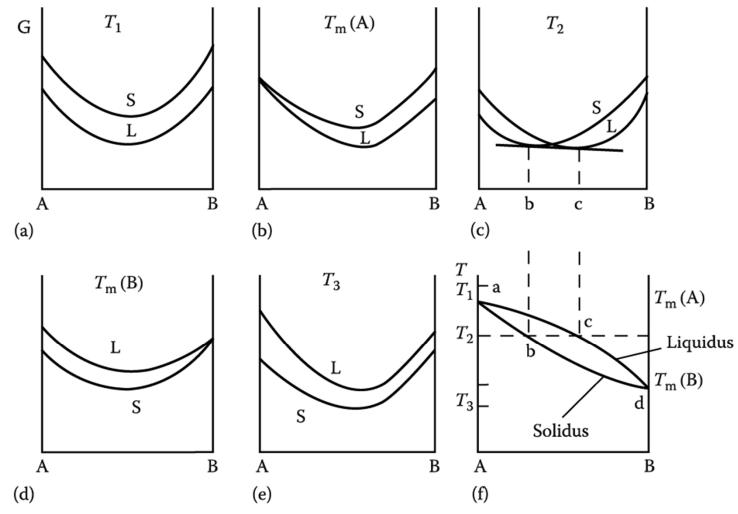
1) Simple Phase Diagrams

- 1) Variation of temp.: G^L > G^s
- 2) Decrease of curvature of G curve
 - (: decrease of -T ΔS_{mix} effect)

Assumption:

- (1) completely miscible in solid and liquid.
- (2) Both are ideal soln.
- (3) $T_m(A) > T_m(B)$

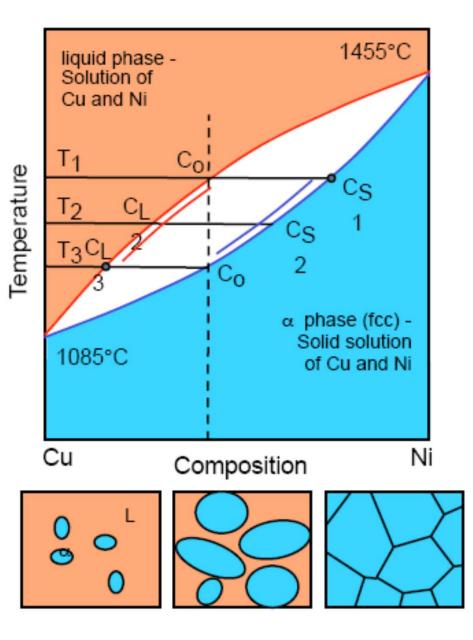
(4)
$$T_1 > T_m(A) > T_2 > T_m(B) > T_3$$



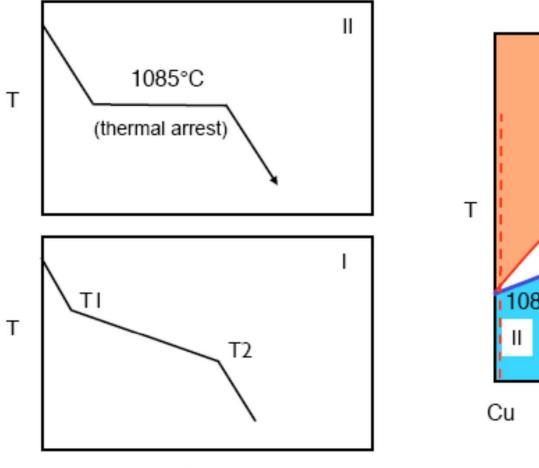
1) Simple Phase Diagrams

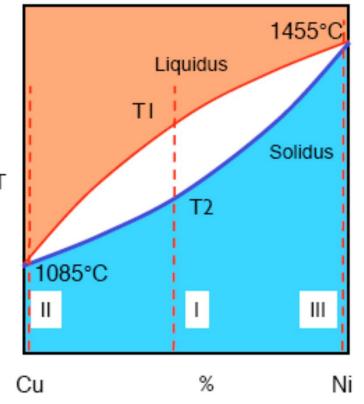
The simplest type of binary phase diagrams is the isomorphous system, in which the two constituents form a continuous solid solution over the entire composition range. An example is the Ni-Cu system.

Solidification of alloy C_0 starts on cooing at T₁. The first solid formed has a composition of C_{s1} and the liquid C_0 . On further cooling the solid particles grow larger in size and change their composition to C_{s2} and then C_0 , following the solidus whereas the liquid decrease in volume and changes its composition from C_0 to C_{L3} following the liquidus. The solidification completes at T₃.



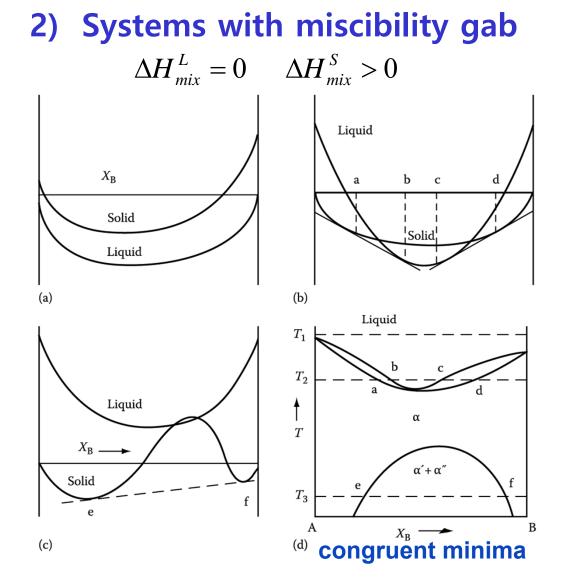
Cooling Curves determination of Phase diagrams





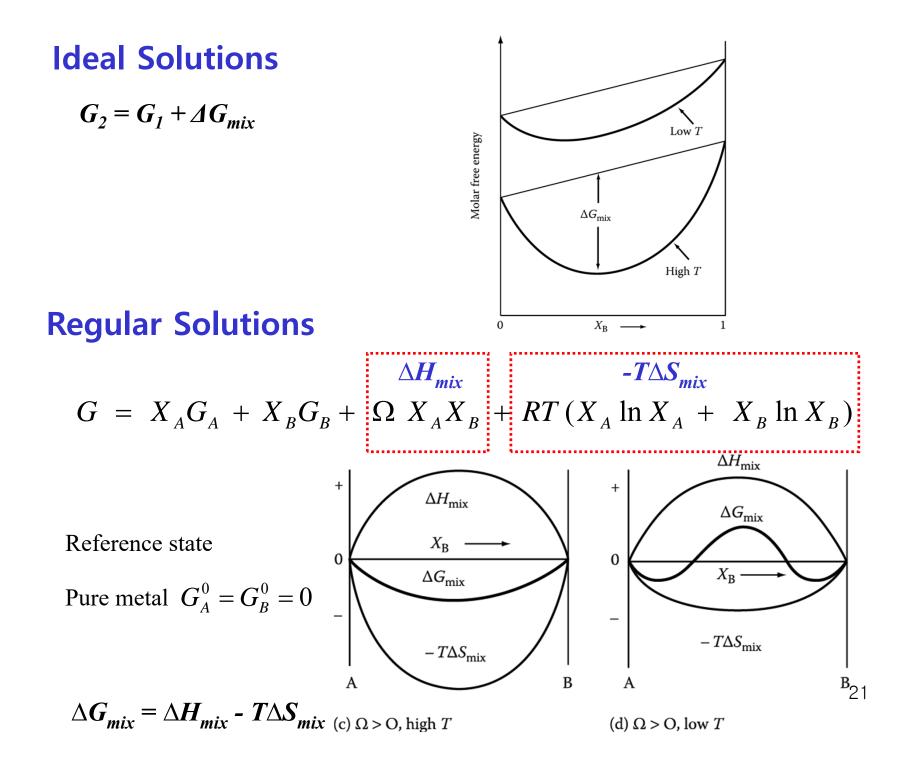
t

Q8: How equilibrium is affected by temperature in systems with miscibility gap?



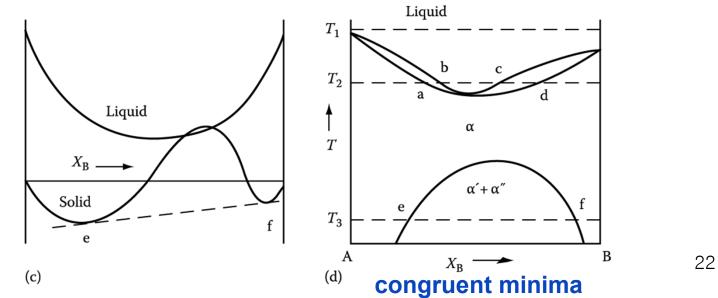
How to characterize G^s mathematically in the region of miscibility gap between e and f?

20



2) Systems with miscibility gab $\Delta H_{mix}^{L} = 0 \qquad \Delta H_{mix}^{S} > 0$

- When A and B atoms dislike each other, $\Delta H_{mix} > 0$
- In this case, the free energy curve at low temperature has a region of negative curvature, $\frac{d^2G}{dX_p^2} < 0$
- This results in a 'miscibility gap' of α ' and α " in the phase diagram



2) Variant of the simple phase diagram

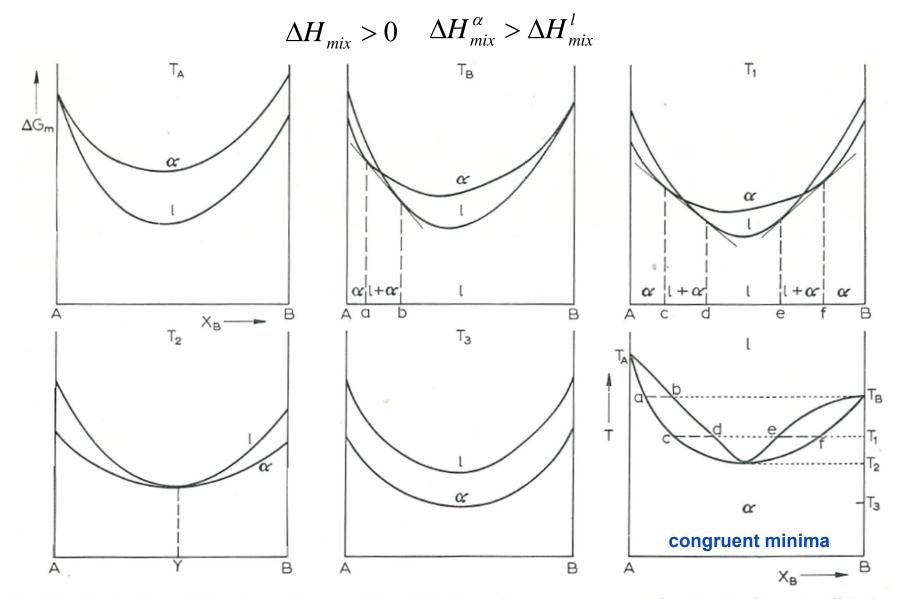


Fig. 30. Derivation of the phase diagram (Fig. 29b) from free energy curves for the liquid and solid phases. $T_A > T_B > T_1 > T_2 > T_3$.

Q9: How equilibrium is affected by temperature in simple eutectic systems?

4) Simple Eutectic Systems $\Delta H_{mix}^{L} = 0$ $\Delta H_{mix}^{S} >> 0$

ΔH_m>>0 and the miscibility gap extends to the melting temperature.
 (when both solids have the same structure.)

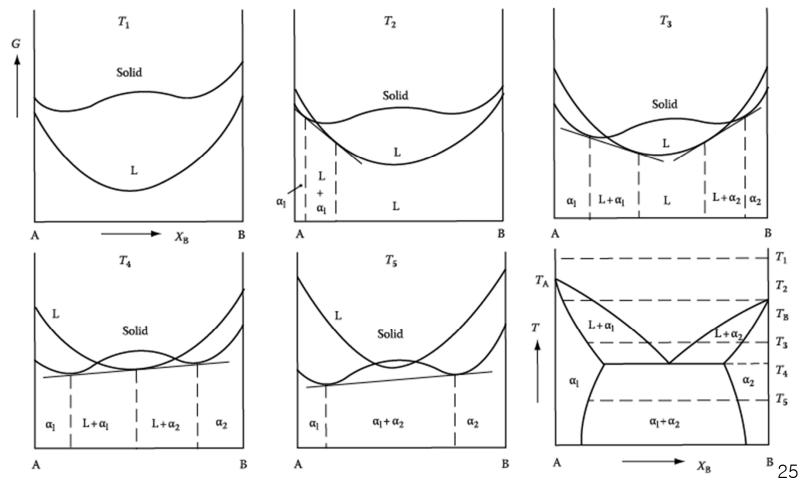


Fig. 1.32 The derivation of a eutectic phase diagram where both solid phases have the same crystal structure.

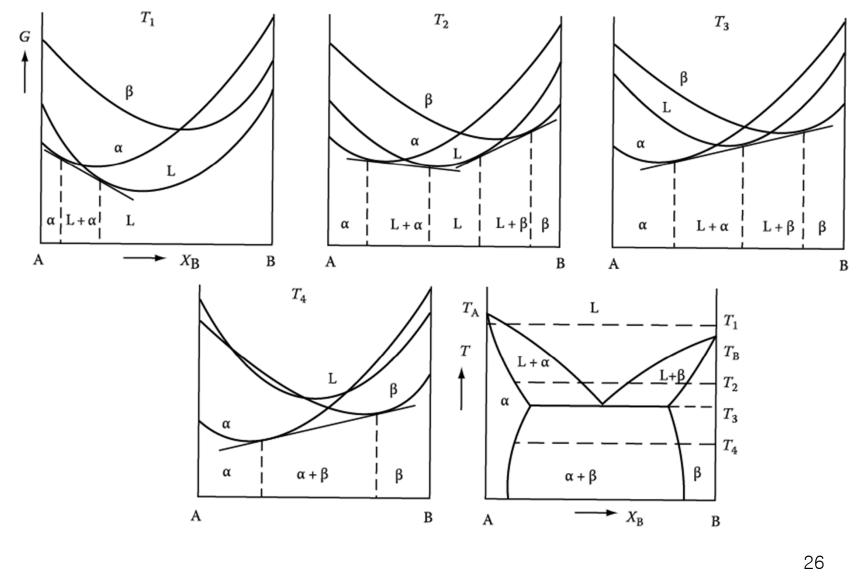
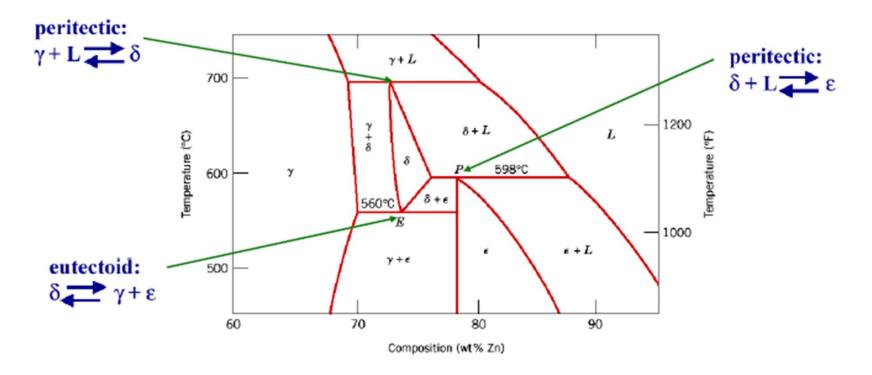


Fig. 1.32 The derivation of a eutectic phase diagram where each solid phases has a different crystal structure.

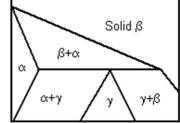
Cu-Zn Phase Diagram

Eutectoid and Peritectic Reactions



<u>Eutectoid</u>: one solid phase transforms into two other solid phases upon cooling <u>Peritectic</u>: one solid and one liquid phase transform into another solid phase upon cooling

<u>Peritectoid</u>: two other solid phases transform into another solid phase upon cooling



2) Variant of the simple phase diagram

 $\Delta H_{mix} < 0$

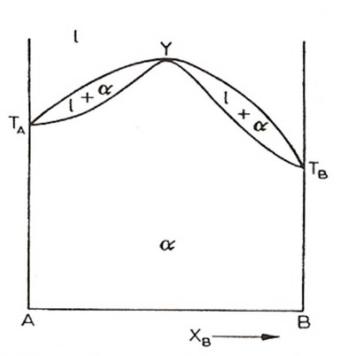


Fig. 32. Phase diagram with a maximum in the liquidus.

congruent maxima

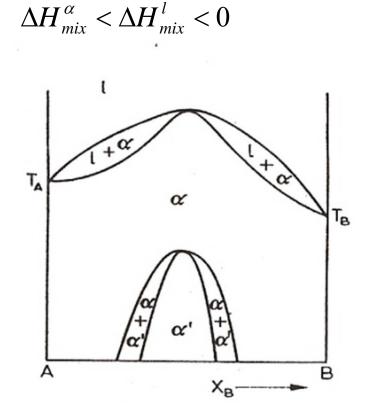
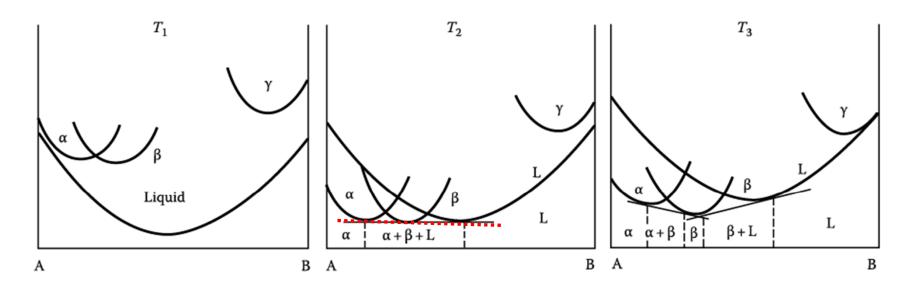
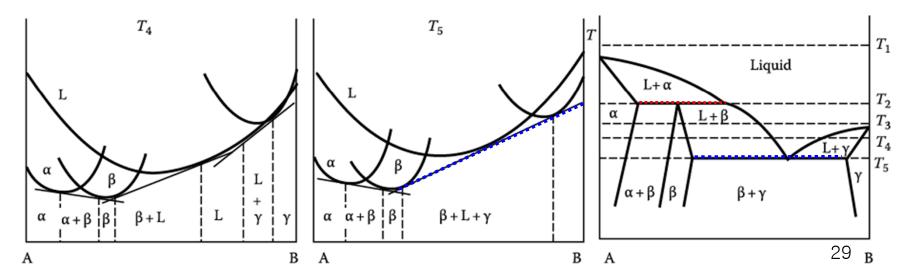


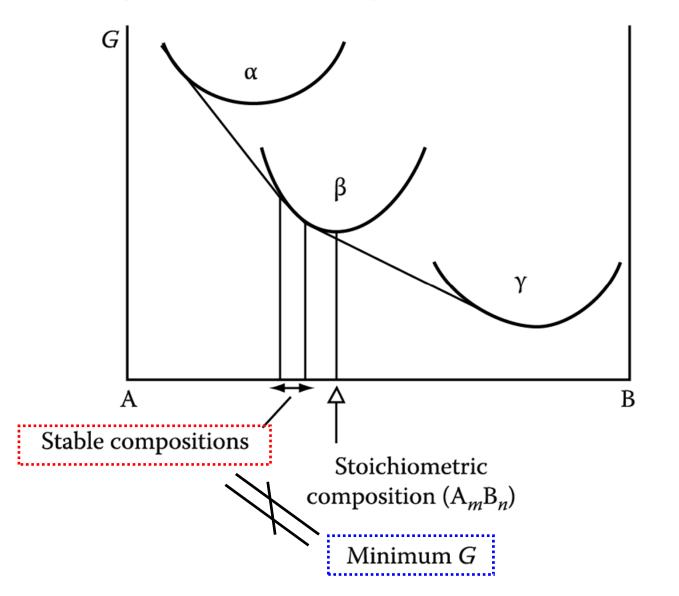
Fig. 33. Appearance of an ordered α' phase at low temperatures.

5) Phase diagrams containing intermediate phases



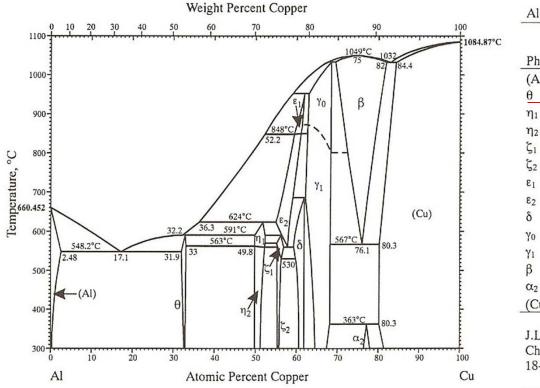


5) Phase diagrams containing intermediate phases



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θ phase in the Cu-Al system is usually denoted as CuAl₂ although the composition X_{Cu}=1/3, X_{Al}=2/3 is not covered by the θ field on the phase diagram.



				Struktur-	
Phase	Composition, at.% Cu	Pearson symbol	Space group	bericht designation	Prototype
(Al)	0 to 2.48	cF4	$Fm\overline{3}m$	A1	Cu
θ	31.9 to 33.0	tI12	I4/mcm	C16	Al ₂ Cu
η_1	49.8 to 52.4	oP16 or oC16	Pban or Cmmm		
η_2	49.8 to 52.3	mC20	Cm/2 .		
ζ1	55.2 to 56.8	hP42	P6/mmm		
ζ2	55.2 to 56.3	<i>m**</i>			
ε1	59.4 to 62.1	C**			
ε2	55.0 to 61.1	hP4	P63/mmc	$B8_1$	NiAs
δ	59.3 to 61.9	hR^*	$R\overline{3}m$		
Yo	63 to 68.5	cI52	$I\overline{4} 3m$	$D8_2$	Cu_5Zn_8
Y1	62.5 to 68.5	cP52	$P\overline{4}3m$	$D8_3$	Al ₄ Cu ₉
β	69.5 to 82	cI2	$Im \overline{3}m$	A2	W
α2	76.5 to 78				
(Cu)	80.3 to 100	cF4	$Fm\overline{3}m$	A1	Cu

J.L. Murray, *Phase Diagrams of Binary Copper Alloys*, P.R. Subramanian, D.J. Chakrabarti, and D.E. Laughlin, ed., ASM International, Materials Park, OH, 18-42 (1994)

X.L. Liu, I. Ohnuma, R. Kainuma, and K. Ishida, J. Alloys Compds, 264, 201-208 (1998)

Al-Cu

Summary I: Binary phase diagrams

1) Simple Phase Diagrams

Both are ideal soln. \rightarrow 1) Variation of temp.: $G^{L} > G^{s}$ 2) Decrease of curvature of G curve (\because decrease of $-T\Delta S_{mix}$ effect)

2) Systems with miscibility gap $\Delta H_{mix}^{L} = 0$ $\Delta H_{mix}^{S} > 0$ 1)Variation of temp.: **G**^L > **G**^s 2)Decrease of curvature of G curve + Shape change of G curve by H

- **4) Simple Eutectic Systems** $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} >> 0$ \rightarrow miscibility gap extends to the melting temperature.
- **3) Ordered Alloys** $\Delta H_{mix}^{L} = 0$ $\Delta H_{mix}^{S} < 0$ $\Delta H_{mix} < 0 \rightarrow A$ atoms and B atoms like each other. \rightarrow Ordered alloy at low T

 $\Delta H_{mix} \ll 0 \rightarrow$ The ordered state can extend to the melting temperature.

5) Phase diagrams containing intermediate phases

Stable composition **†** Minimum G with stoichiometric composition

The Gibbs Phase Rule

Degree of freedom (number of variables that can be varied independently)

= the number of variables – the number of constraints

- Number of phases : p, number of components : c,
- # of controllable variable : composition (c-1)p, temperature : p, pressure : p
- # of restrictions :

(p-1)c from chemical equilibrium

p-1 from thermal equilibrium

p-1 from mechanical equilibrium $P^a = P^\beta = P^\gamma = \dots = P^p$

$$\mu_i^a = \mu_i^\beta = \mu_i^\gamma = \dots = \mu_i^p$$
$$T^a = T^\beta = T^\gamma = \dots = T^p$$

$$f = (c-1)p + p + p - (p-1)c - (p-1) - (p-1) = c - p + 2$$
$$f = c - p + 2$$

- If pressure is constant : f = (c-1)p + p - (p-1)c - (p-1) = c - p + 1

The Gibbs Phase Rule

In chemistry, Gibbs' phase rule describes the <u>possible number of</u> <u>degrees of freedom (F) in a closed system at equilibrium</u>, in terms of the number of separate phases (P) and the number of chemical components (C) in the system. It was deduced from thermodynamic principles by Josiah Willard Gibbs in the 1870s.

Gibbs phase rule

F =C+N-P

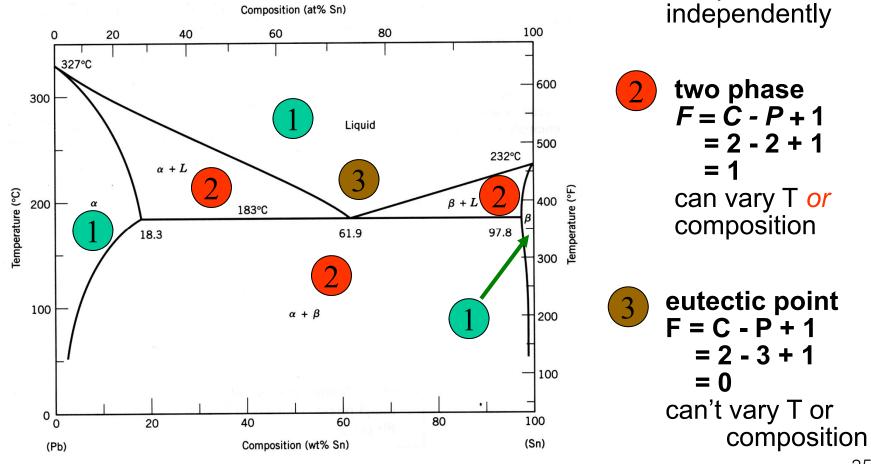
F: degree of freedom C: number of chemical variables N: number of non-chemical variables P: number of phases

In general, Gibbs' rule then follows, as:

F = C - P + 2 (from T, P).

From Wikipedia, the free encyclopedia

The Gibbs Phase Rule For Constant Pressure, P + F = C + 1



single phase

= 2 - 1 + 1

can vary T and

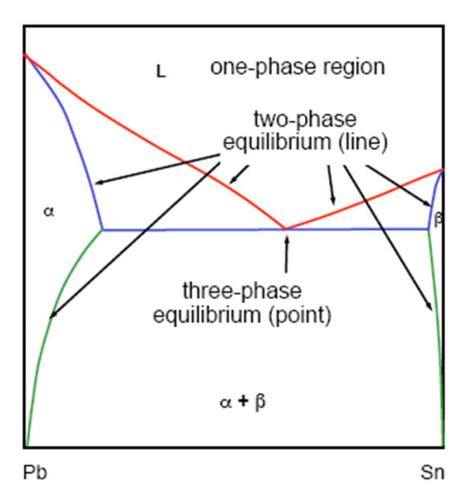
composition

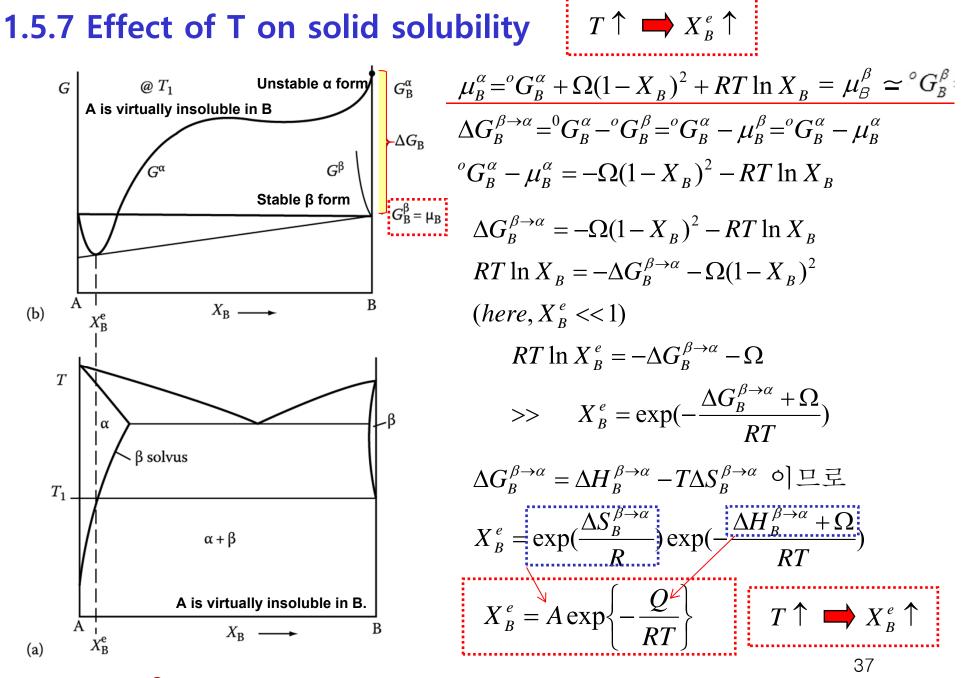
F = C - P + 1

= 2

The Gibbs Phase Rule

Application of Gibbs phase rule: For a binary system at ambient pressure: C=2 (2 elements) N=1 (temperature, no pressure) For single phase: F=2: % and T (a region) For a 2-phase equilibrium: F=1: % or T (a line) For a 3-phase equilibrium: F=0, (invariant point)





Q: heat absorbed (enthalpy) when 1 mole of β dissolves in A rich α as a dilute solution.

* Limiting forms of eutectic phase diagram

The solubility of one metal in another may be so low.

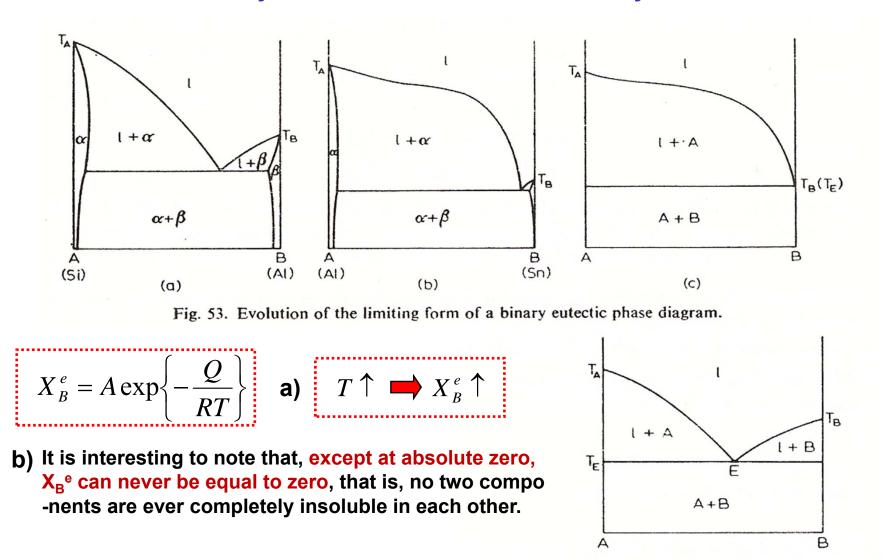
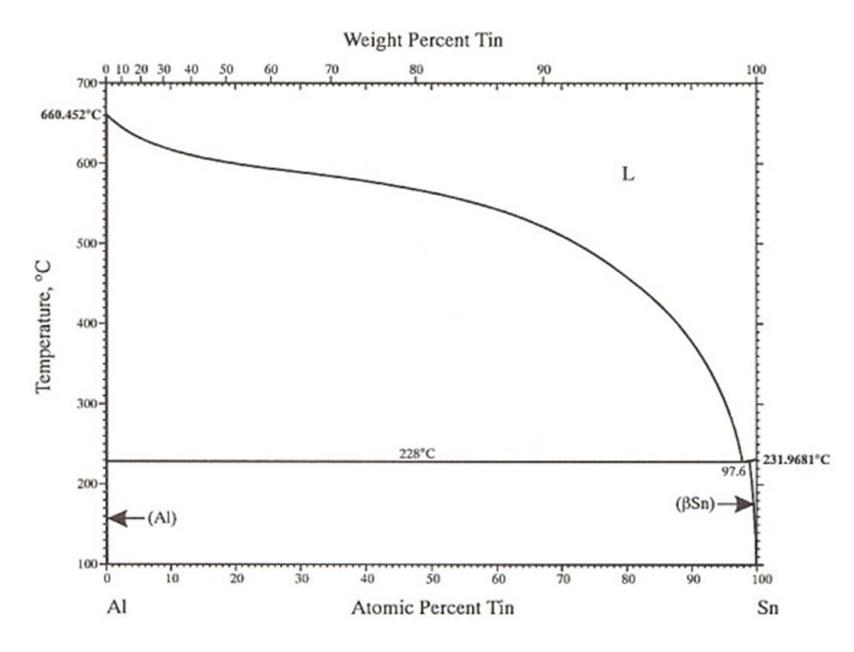


Fig. 54. Impossible form of a binary eutectic phase diagram.



a) 평형에 미치는 공공의 영향

1.5.8. Equilibrium Vacancy Concentration $\Delta G = \Delta H - T \Delta S$

G of the alloy will depend on the concentration of vacancies and X_V^e will be that which gives the minimum free energy.

1) <u>Vacancies increase the internal energy of crystalline metal</u> due to broken bonds formation. (Here, vacancy-vacancy interactions are ignored.)

$$\Delta H \cong \Delta H_V X_V$$

- 2) Vacancies increase entropy because they change the thermal vibration frequency and also the configurational entropy. Small change due to changes in the vibrational frequencies "Largest contribution"
- Total entropy change is thus

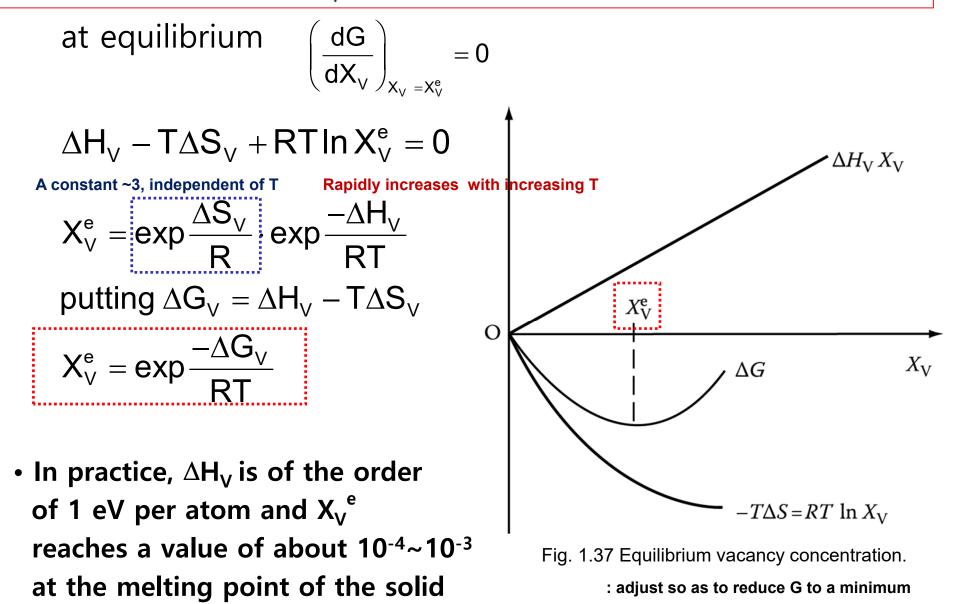
$$\Delta S = \Delta S_{v} X_{v} - R\{X_{v} \ln X_{v} + (1 - X_{v}) \ln(1 - X_{v})\}$$

The molar free energy of the crystal containing X_v mol of vacancies

$$\mathbf{G} = \mathbf{G}_{\mathsf{A}} + \Delta \mathbf{G} = \mathbf{G}_{\mathsf{A}} + \Delta \mathbf{H}_{\mathsf{V}} \mathbf{X}_{\mathsf{V}} - \mathsf{T} \Delta \mathbf{S}_{\mathsf{V}} \mathbf{X}_{\mathsf{V}} + \mathsf{RT} \{ \mathbf{X}_{\mathsf{V}} \ln \mathbf{X}_{\mathsf{V}} + (1 - \mathbf{X}_{\mathsf{V}}) \ln(1 - \mathbf{X}_{\mathsf{V}}) \}$$



Equilibrium concentration X_v^e will be that which gives the minimum free energy.

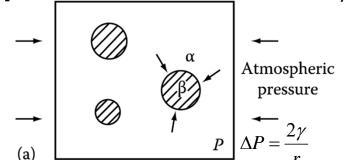


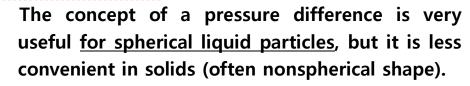
The G curves so far have been based on the molar Gs of infinitely large amounts of material of a perfect single crystal. Surfaces, GBs and interphase interfaces have been ignored.

1.6 Influence of Interfaces on Equilibrium - b) 평형에 미치는 계면의 영향

$$\Delta G = \Delta P \cdot V \implies \Delta G = \frac{2\gamma V_m}{r}$$

Extra pressure ΔP due to curvature of the α/β





dG =
$$\Delta G_{\gamma} dn = \gamma dA$$
 $\Delta G_{\gamma} = \gamma dA/dn$
Since n=4 $\pi r^3/3V_m$ and A = 4 πr^2 $\Delta G = \frac{2\gamma V_m}{r}$

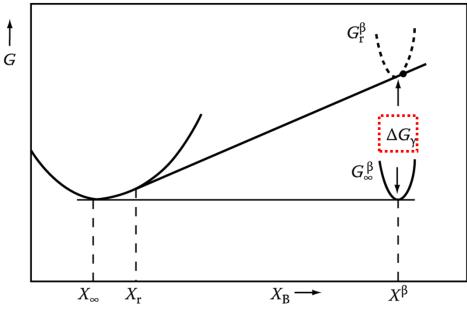


Fig. 1.38 The effect of interfacial E on the solubility of small particle

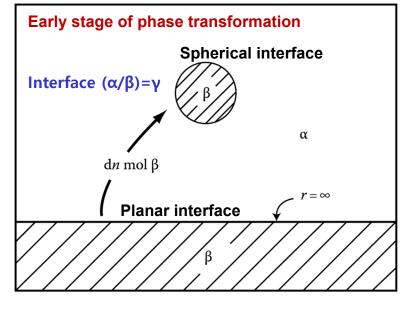


Fig. 1.39 Transfer of dn mol of $\boldsymbol{\beta}$ from large to a small particle.

Gibbs-Thomson effect (capillarity effect):

Free energy increase due to interfacial energy

Quite large solubility differences can arise for particles in the range r=1-100 nm. However, for particles visible in the light microscope (r>1um) capillarity effects are very small.

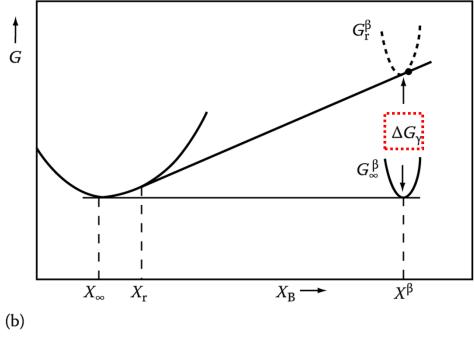


Fig. 1.38 The effect of interfacial energy on the solubility of small particles.

$$X_{B}^{e} = A \exp\left\{-\frac{Q}{RT}\right\}$$

$$X_{B}^{e} = \exp\left(-\frac{\Delta G_{B} + \Omega}{RT}\right)$$

$$X_{B}^{r=\infty} = \exp\left(-\frac{\Delta G_{B} + \Omega}{RT}\right)$$

$$X_{B}^{r=r} = \exp\left(-\frac{\Delta G_{B} + \Omega - 2\gamma V_{m}/r}{RT}\right)$$

$$= X_{B}^{r=\infty} \exp\left(\frac{2\gamma V_{m}}{RT}\right)$$

For small values of the exponent,

$$\frac{X_B^{r=r}}{X_B^{r=\infty}} = \exp(\frac{2\gamma V_m}{RTr}) \approx 1 + \frac{2\gamma V_m}{RTr}$$

Ex) $\gamma = 200 \text{mJ/m}^2$, $V_m = 10^{-5} \text{ m}^3$, T = 500 K $\frac{X_r}{X_{\infty}} = 1 + \frac{1}{r(nm)}$ For r=10 nm, solubility~10% increase

1.8 Additional Thermodynamic Relationships for Binary Solutions

Gibbs-Duhem equation: Calculate the change in (dµ) that results from a change in (dX)

$$G = \frac{d\mu_{A}}{d\mu_{B}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{d\mu_{A}}{d\mu_{A}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{d\mu_{A}}{d\mu_{A}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{d\mu_{A}}{d\mu_{B}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{d\mu_{A}}{d\mu_{B}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{d\mu_{B}}{d\lambda_{B}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{dG}{d\lambda_{B}} d(\mu_{B} - \mu_{A})$$

$$G = \frac{dG}{d\lambda_{B$$

Additional Thermodynamic Relationships for Binary Solutions

The Gibbs-Duhem Equation 합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화(dµ)를 계산 be able to calculate the change in chemical potential (dµ) that result from a change in alloy composition (dX).

① For a regular solution,

(2)

$$G = X_{A}G_{A} + X_{B}G_{B} + \Omega X_{A}X_{B} + RT(X_{A}\ln X_{A} + X_{B}\ln X_{B})$$

$$\frac{d^{2}G}{dX^{2}} = \frac{RT}{X_{A}X_{B}} - 2\Omega$$
For a ideal solution, $\Omega = 0$, $\frac{d^{2}G}{dX^{2}} = \frac{RT}{X_{A}X_{B}}$

$$\textcircled{O} \quad \begin{array}{l} \text{Different form} \\ \text{Eq. 1.65} \end{array} \quad \mu_{B} = G_{B} + RT\ln a_{B} = G_{B} + RT\ln \gamma_{B}X_{B}$$

$$\overbrace{V_{B}=a_{B}/X_{B}} \longrightarrow \end{array}$$
Differentiating With respect to X_{B}, $\begin{array}{l} \frac{d\mu_{B}}{dX_{B}} = \frac{RT}{X_{B}} \left\{ 1 + \frac{X_{B}}{\gamma_{B}} \frac{d\gamma_{B}}{dX_{B}} \right\} = \frac{RT}{X_{B}} \left\{ 1 + \frac{d\ln \gamma_{B}}{d\ln X_{B}} \right\}$

$$45$$

45

$$\frac{d\mu_B}{dX_B} = \frac{RT}{X_B} \left\{ 1 + \frac{X_B}{\gamma_B} \frac{d\gamma_B}{dX_B} \right\} = \frac{RT}{X_B} \left\{ 1 + \frac{d\ln\gamma_B}{d\ln X_B} \right\}$$
 Eq. 1.69

a similar relationship can be derived for $d\mu_A/dX_B$

$$-X_{A}d\mu_{A} = X_{B}d\mu_{B} = RT\left\{1 + \frac{d\ln\gamma_{A}}{d\ln X_{A}}\right\}dX_{B} = RT\left\{1 + \frac{d\ln\gamma_{B}}{d\ln X_{B}}\right\}dX_{B}$$
Eq. 1.70
$$-X_{A}d\mu_{A} = X_{B}d\mu_{B} = X_{A}X_{B}\frac{d^{2}G}{dX^{2}}dX_{B}$$
Eq. 1.65

The Gibbs-Duhem Equation

$$X_A X_B \frac{d^2 G}{dX^2} = RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\}$$

be able to calculate the change in chemical potential $(d\mu)$ that result from a change in alloy composition (dX).

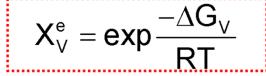
Total Free Energy Decrease per Mole of Nuclei ΔG_{n} : 변태를 위한 전체 구동력/핵생성을 위한 구동력은 아님 **Driving Force for Precipitate Nucleation** $\alpha \rightarrow \alpha + \beta$ $\Delta \mathbf{G}_{\mathbf{V}}$ $\Delta G_1 = \mu_A^{\alpha} X_A^{\beta} + \mu_B^{\alpha} X_B^{\beta}$ α : Decrease of total free E of system by removing a small amount of material **-** β $\alpha + \beta$ with the nucleus composition (X_{B}^{β}) (P point) T_2 $\Delta G_2 = \mu_A^\beta X_A^\beta + \mu_B^\beta X_B^\beta$: Increase of total free E of system (a) A X_{e} X_0 X^{β} by forming β phase with composition X_{R}^{β} $X_{\rm B} \longrightarrow$ В (Q point) $@T_2$ $\Delta G_n = \Delta G_2 - \Delta G_1$ (length PQ) μ_{B}^{α} G G^{α} $\Delta G_{V} = \frac{\Delta G_{n}}{V}$ per unit volume of β : driving force for β precipitation ΔG_n For dilute solutions, IG^β μβ ΔG_0 μβ $\Delta G_{V} \propto \Delta X$ where $\Delta X = X_{0} - X_{e}$ μ^a_A $\Delta G_{V} \propto \Delta X \propto (\Delta T)$ 47 \propto undercooling below T_a (b) 0 $X_{\rm R}$ – 1

Summary II: Binary phase diagrams

- Gibbs Phase Rule Gibbs' Phase Rule allows us to construct phase diagram to represent and interpret phase equilibria in heterogeneous geologic systems.
- Effect of Temperature on Solid Solubility

$$X_B^e = A \exp\left\{-\frac{Q}{RT}\right\}$$
 a) $T \uparrow \implies X_B^e \uparrow$ **b)** X_B^e can never be equal to zero.

• Equilibrium Vacancy Concentration



• Influence of Interfaces on Equilibrium

$$\Delta G = \frac{2\gamma V_m}{r}$$
 Gibbs-Thomson effect

• Gibbs-Duhem Equation: Be able to calculate the change in

chemical potential that result from a change in alloy composition.

$$X_A X_B \frac{d^2 G}{dX^2} = RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\}$$

합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화**(d**μ) 를 계산

Topic proposal for materials design

Please submit 3 materials that you want to explore for materials design and do final presentations on in this semester. Please make sure to thoroughly discuss why you chose those materials (up to 1 page on each topic). The proposal is due by September 25 on eTL.

Ex) stainless steel/ graphene/ OLED/ Bio-material/ Shape memory alloy Bulk metallic glass, etc.